

# Vladimir Evstigneev

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/3008594/publications.pdf>

Version: 2024-02-01

4  
papers

12  
citations

2682572

2  
h-index

2272923

4  
g-index

4  
all docs

4  
docs citations

4  
times ranked

9  
citing authors

#	ARTICLE	IF	CITATIONS
1	Growth of arsenic-doped cadmium telluride epilayers by metalorganic chemical vapor deposition. Inorganic Materials, 2016, 52, 1210-1214.	0.8	5
2	Electrophysical Properties of p-Type Undoped and Arsenic-Doped $\text{Hg}_{1-x}\text{Cd}_x\text{Te}$ Epitaxial Layers with $x \sim 0.4$ Grown by the MOCVD Method. Semiconductors, 2018, 52, 702-707.	0.5	4
3	Growth of Arsenic-Doped $\text{Hg}_{1-x}\text{Cd}_x\text{Te}$ ( $x \sim 0.4$ ) Epilayers by Metalorganic Chemical Vapor Deposition. Inorganic Materials, 2019, 55, 984-988.	0.8	2
4	Arsenic Doping Upon the Deposition of CdTe Layers from Dimethylcadmium and Diisopropyltellurium. Semiconductors, 2021, 55, 7-13.	0.5	1